

Abstracts

A 94 GHz Monolithic Downconverter in a MESFET Technology

J.-M. Dieudonne, R. Rittmeyer, B. Adelseck and A. Colquhoun. "A 94 GHz Monolithic Downconverter in a MESFET Technology." 1992 Microwave and Millimeter-Wave Monolithic Circuits Symposium Digest 92.1 (1992 [MCS]): 69-72.

A fully monolithic GaAs 94 GHz downconverter consisting of a single balanced diode mixer and a two-stage IF amplifier has been fabricated in a MESFET technology on a single chip. A conversion gain of 14.5 dB combined with a double side band noise figure of 6.5 dB has been achieved at 94 GHz. This is the first developed single chip MMIC 94 GHz downconverter in a MESFET technology.

[Return to main document.](#)